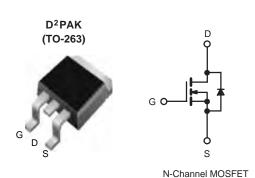


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# N-Channel 200-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>(BR)DSS</sub> (V)	$r_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
200	0.026 at V <sub>GS</sub> = 10 V	80		





Top View

### **FEATURES**

- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- Low Thermal Resistance Package
- 100 %  $R_{g}$  and UIS tested

#### **APPLICATIONS**

- LCD/LED TV
- Consumer Appliances
- Lighting
- AC-DC Power Supply

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	$V_{DS}$	200	V		
Gate-Source Voltage	Gate-Source Voltage			ľ	
Continuous Drain Current	$V_{GS}$ at 10 V $T_{C} = 25  ^{\circ}C$ $T_{C} = 100  ^{\circ}C$	1_	80 <sup>a</sup>	А	
Continuous Drain Guirent	$T_C = 100 ^{\circ}C$	I <sub>D</sub>	75 <sup>a</sup>		
Pulsed Drain Current	I <sub>DM</sub>	320	Ī		
Single Pulse Avalanche Energy	E <sub>AS</sub>	185	mJ		
Avalanche Current	I <sub>AR</sub>	77	Α		
Repetiitive Avalanche Energy	E <sub>AR</sub>	45	mJ		
Maximum Power Dissipation	T <sub>C</sub> = 25 °C	Pn	395	w	
Waximum Tower Dissipation	T <sub>A</sub> = 25 °C <sup>b</sup>	r D	3.9 <sup>c</sup>	T **	
Peak Diode Recovery dV/dt	dV/dt	5.0	V/ns		
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 55 to + 175	°C		
Soldering Recommendations (Peak Temperature)		300	]		

THERMAL RESISTANCE RATINGS						
PARAMETER	SYMBOL	TYP.	MAX.	UNIT		
Maximum Junction-to-Ambient (PCB Mounted, Steady-State)	R <sub>thJA</sub>	-	32	°C/W		
Maximum Junction-to-Case (Drain)	$R_{thJC}$	-	0.43			

- a. Package limited.
- b. When Mounted on 1" square PCB (FR-4 material).
- c. See SOA curve for voltage derating.



PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		-	-	.,	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	-	4	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA	
		V <sub>DS</sub> = 160 V, V <sub>GS</sub> = 0 V	-	-	1	μА	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 125 ^{\circ}\text{C}$	-	-	100		
		V <sub>DS</sub> = 160 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 175 °C	-	-	2	mA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	80	-	-	Α	
Drain-Source On-State Resistance a	D	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A	-	0.026	0.029		
	R <sub>DS(on)</sub>	$V_{GS} = 7.5 \text{ V}, I_D = 20 \text{ A}$	-	0.029	0.035	Ω	
Forward Transconductance a	9fs	V <sub>DS</sub> = 20 V, I <sub>D</sub> = 30 A	-	15	-	S	
Dynamic <sup>b</sup>				1			
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 100 V, f = 1 MHz	-	13050	-	pF	
Output Capacitance	Coss		-	550	-		
Reverse Transfer Capacitance	C <sub>rss</sub>		-	96	-		
Total Gate Charge <sup>c</sup>	Qg		80	90	150	nC	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	-	23	-		
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>		-	35	-		
Gate Resistance	R <sub>g</sub>	f = 1 MHz	-	4.1	-	Ω	
Turn-On Delay Time °	t <sub>d(on)</sub>		-	15	-		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = 100 \text{ V}, R_L = 1.67 \Omega I_D$	-	25	-		
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>	$\cong$ 30 A, V <sub>GEN</sub> = 10 V, R $_g$ = 1 $\Omega$	=	27	-	ns	
Fall Time <sup>c</sup>	t <sub>f</sub>		-	9	-		
Drain-Source Body Diode Ratings ar	nd Characteris	stics <sup>b</sup> (T <sub>C</sub> = 25 °C)					
Pulsed Current (t = 100 μs)	I <sub>SM</sub>		-	-	320	Α	
Forward Voltage a	V <sub>SD</sub>	I <sub>F</sub> = 20 A, V <sub>GS</sub> = 0 V	-	0.75	1.2	V	
Reverse Recovery Time	t <sub>rr</sub>		-	85	-	ns	
Peak Reverse Recovery Charge	IRM(REC)	$I_F = 20 \text{ A}, \text{ d/dt} = 100 \text{ A/}\mu\text{s}$	-	5	-	Α	
Reverse Recovery Charge	Q <sub>rr</sub>		-	0.21	-	μC	

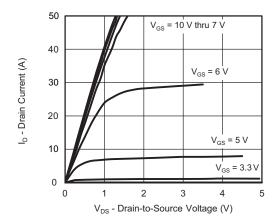
#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

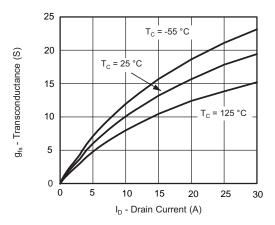
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



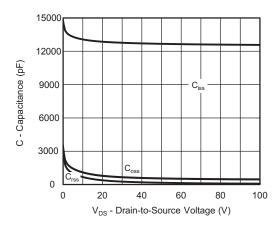
# **TYPICAL CHARACTERISTICS** ( $T_A = 25$ °C, unless otherwise noted)



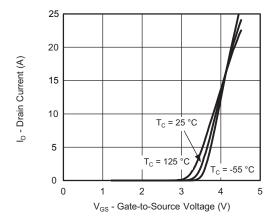
#### **Output Characteristics**



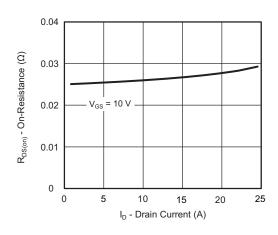
Transconductance



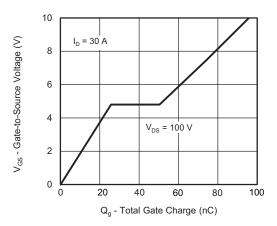
Capacitance



**Transfer Characteristics** 



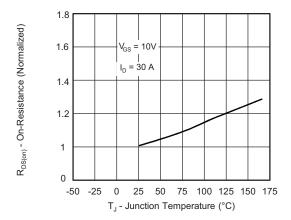
On-Resistance vs. Drain Current



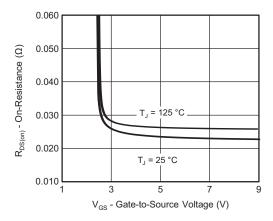
**Gate Charge** 



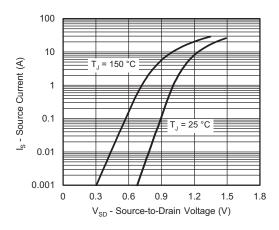
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



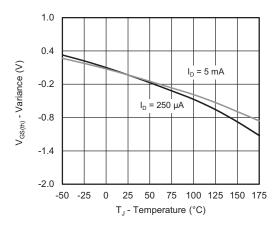
On-Resistance vs. Junction Temperature



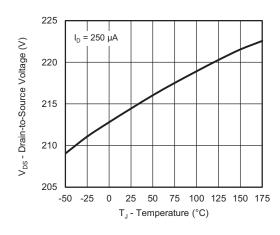
On-Resistance vs. Gate-to-Source Voltage



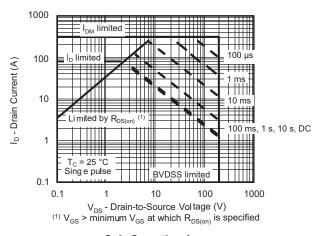
Source Drain Diode Forward Voltage



Threshold Voltage



**Drain Source Breakdown vs. Junction Temperature** 



Safe Operating Area



**THERMAL RATINGS** ( $T_A = 25$  °C, unless otherwise noted)

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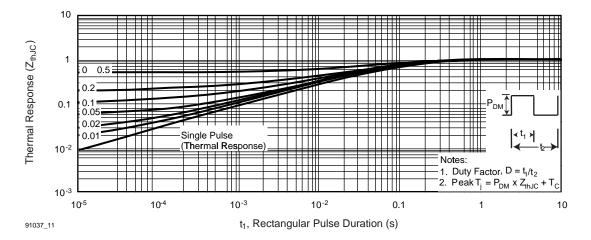
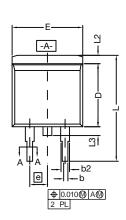
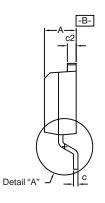


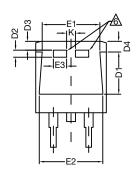
Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case



# TO-263 (D<sup>2</sup>PAK): 3-LEAD

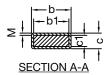








**DETAIL A (ROTATED 90°)** 



10°,	: -][_	<u>∓</u>
1	L1	<u>T</u>

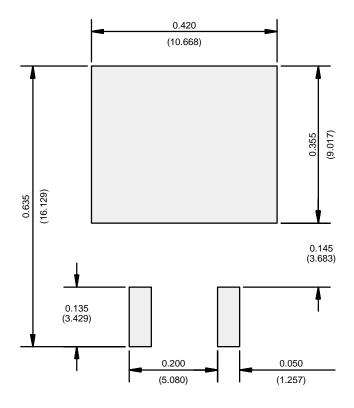
### Notes

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. \*: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement. This feature is for thick lead.

	INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.
Α		0.160	0.190	4.064	4.826
	b	0.020	0.039	0.508	0.990
	b1	0.020	0.035 0.508	0.508	0.889
	b2	0.045	0.055	1.143	1.397
c*	Thin lead	0.013	0.018	0.330	0.457
	Thick lead	0.023	0.028	0.584	0.711
c1	Thin lead	0.013	0.017	0.330	0.431
CI	Thick lead	0.023	0.027	0.584	0.685
	c2	0.045	0.055	1.143	1.397
	D	0.340	0.380	8.636	9.652
	D1	0.220	0.240	5.588	6.096
	D2	0.038	0.042	0.965	1.067
	D3	0.045	0.055	1.143	1.397
	D4	0.044	0.052	1.118	1.321
	Е	0.380	0.410	9.652	10.414
	E1	0.245	=	6.223	=
	E2	0.355	0.375	9.017	9.525
	E3	0.072	0.078	1.829	1.981
	е	0.100 BSC		2.54 BSC	
	K	0.045	0.055	1.143	1.397
L		0.575	0.625	14.605	15.875
L1		0.090	0.110	2.286	2.794
L2		0.040	0.055	1.016	1.397
L3		0.050	0.070	1.270	1.778
L4		0.010 BSC		0.254 BSC	
	М	-	0.002	-	0.050
ECN: T13-0707-Rev. K, 30-Sep-13					

DWG: 5843

## RECOMMENDED MINIMUM PADS FOR D<sup>2</sup>PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)





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